

InAsSb photovoltaic detectors



P13894 series

High-speed response and high sensitivity infrared detectors (up to 10 µm band)

The P13894 series are photovoltaic type detectors that have achieved high sensitivity in the spectral range up to 10 µm band. These products are environmentally friendly infrared detectors and do not use mercury or cadmium, which are substances restricted by the RoHS Directive. They are replacements for previous products that contain these substances. The easily handled non-cooled type and the TE-cooled type capable of stable high S/N measurement are available.

Features

- → High sensitivity
- → High-speed response
- High shunt resistance
- Non-cooled (P13894-011MA)
- RoHS compliant (lead, mercury, cadmium free)

Applications

- Gas detection (SOx, NOx, NH3, O3, etc.)
- **■** Radiation thermometers
- CO2 laser monitor
- Mid infrared spectroscopy

Options (sold separately)

→ Heatsink for two-stage TE-cooled type A3179-01 **■** Temperature controller for TE-cooled type C1103-04 **→** Amplifier for infrared detector C4159-01

Structure

Parameter	P13894-011MA	P13894-211MA	Unit		
Window material	Ge with AR coating Ge with AR coating		-		
Package	TO-5	TO-8	-		
Cooling	Non-cooled Two-stage TE-cooled		-		
Photosensitive area	1 × 1				
Field of view (FOV)	102	113	degrees		

- Absolute maximum ratings

Parameter	Symbol	Condition	P13894-011MA	P13894-211MA	Unit
Reverse voltage	VR			V	
Operating temperature	Topr	No dew condensation*1	-40 to	°C	
Storage temperature	Tstg	No dew condensation*1	-40 to	°C	

^{*1:} When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

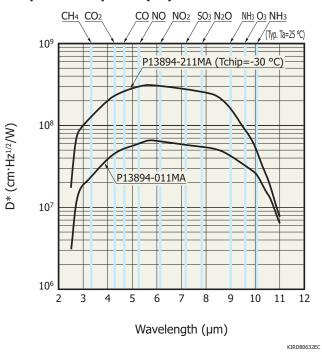
■ Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol Condition	P13894-011MA		P13894-211MA		Unit			
		Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Chip temperature	Tchip			25			-30		°C
Peak sensitivity wavelength	λр		-	5.6	-	-	5.6	-	μm
Cutoff wavelength	λс		9.7	11.0	-	8.9	10.2	-	μm
Photosensitivity	S	$\lambda = \lambda p^{*2}$	1.3	1.9	-	2.8	3.8	-	mA/W
Shunt resistance	Rsh	VR=10 mV	1.5	2.0	-	7.5	10.0	-	kΩ
Detectivity	D*	(λρ, 1200, 1)	3.8×10^{7}	6.5×10^{7}	-	1.8×10^{8}	3.2×10^{8}	-	cm·Hz ^{1/2} /W
Noise equivalent power	NEP	λ=λρ	-	1.5×10^{-9}	2.6×10^{-9}	-	3.1×10^{-10}	5.6×10^{-10}	W/Hz ^{1/2}
Terminal capacitance	Ct	VR=0 V, f=1 MHz	-	0.6	-	-	0.6	-	pF
Rise time	tr	λ 10 to 90%, no window, λ 1.55 µm	-	3	10	-	3	10	ns

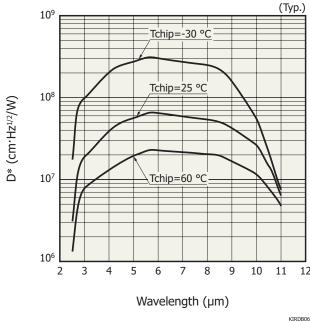
^{*2:} Uniform irradiation on the entire photosensitive area

Note: Uniform irradiation must be applied to the entire photosensitive area during use.

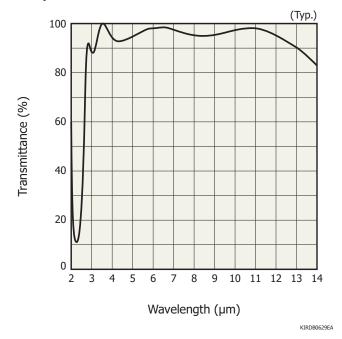
Spectral response (D*)



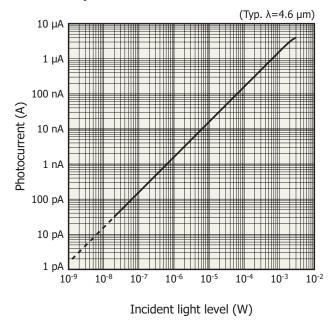
Sensitivity temperature characteristics



Spectral transmittance of window material

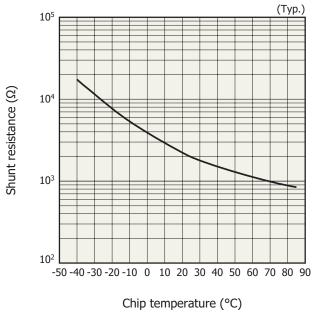


Linearity



KIRDB0630EA

- Shunt resistance vs. chip temperature



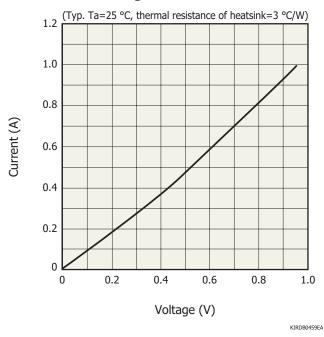
KIRDB0628EA

➡ Specifications of two-stage TE-cooler (Ta=25 °C)

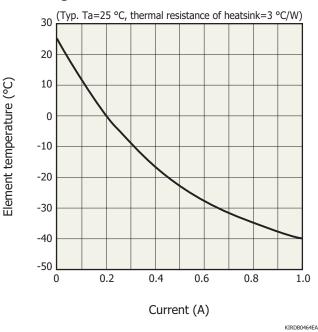
Parameter	Symbol	Min.	Тур.	Max.	Unit
TE-cooler allowable current	Іте тах	-	-	1.0	Α
TE-cooler allowable voltage	VTE max	-	-	1.2	V
Thermistor resistance	Rth	8.1	9.0	9.9	kΩ
Thermistor B constant*5	В	-	3298	-	K
Thermistor power dissipation	Pth	-	-	0.2	mW

^{*5:} T1=25 °C, T2=-30 °C

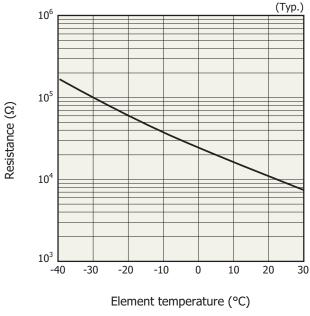
Current vs. voltage characteristics of TE-cooler



- Cooling characteristics of TE-cooler

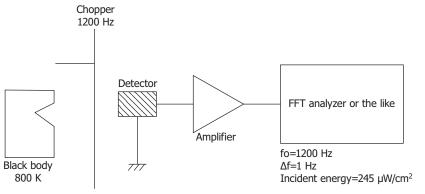


Thermistor temperature characteristics



KIRDB0116EC

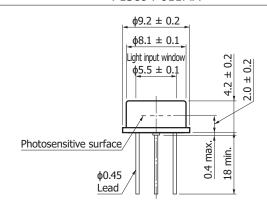
Block diagram for characteristic measurement

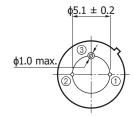


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Dimensional outlines (unit: mm)

P13894-011MA

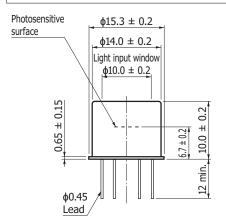


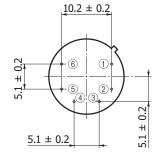




KIRDA0257EB

P13894-211MA





- ① Detector (anode)
- 2 Detector (cathode)
- ③ TE-cooler (-) ④ TE-cooler (+)
- 56 Thermistor

KIRDA0258EB

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Recommended soldering conditions

Soldering temperature: 260°C (once, within 10 s) Solder the lead more than 1mm away from the root.

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Safety consideration
- · Compound opto-semiconductors (photosensors, light emitters)
- Technical note
- · Compound semiconductor photosensors

Information described in this material is current as of October 2023.

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